## NSN 5962-01-549-3681

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View Online at https://aerobasegroup.com/nsn/5962-01-549-3681

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Body Length:
1.060 inches
Body Width:
0.300 inches
Body Height:
0.130 inches
Maximum Power Dissipation Rating:
907.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15 aircraft
Features Provided:
Bipolar and electrostatic sensitive and high speed and 3-state output and schottky
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Current Rating Per Characteristic:
165.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital-bipolar prom 512 x 8
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source and -0.5 volts input and 5.5 volts input
Time Rating Per Chacteristic:
50.00 nanoseconds access
Memory Device Type:
Prom
Memory Capacity:
512 x 8
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

A458a0

